







INA351A SBOSAG2 - JUNE 2023

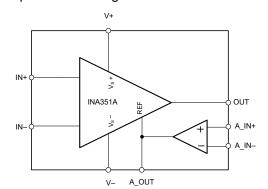
INA351A - Low Power, 1.8-V to 5.5-V Small-Size Instrumentation Amplifier with **Configurable Reference Amplifier**

1 Features

- Fixed gain of 10V/V instrumentation amp with configurable reference amp
- INA performance for 10-bit to 14-bit systems
 - CMRR: 95 dB (typical)
 - Gain error: 0.015% (typical)
 - Bandwidth: 100 kHz (typical)
- Reference amp can be used for:
 - External DC error calibration with servo loop
 - Providing buffered voltage of external circuits
 - Filtering or adjustment of reference voltage
- Ultra-small package option (2mm x 2mm)
- Drives 1 nF with under 10% overshoot (typical)
- Optimized quiescent current: 110 µA (typical)
- Supply range: 1.8 V (±0.9 V) to 5.5 V (±2.75 V)
- Specified temperature range: -40°C to 125°C

2 Applications

- Electrocardiogram
- Pressure transmitter
- Weigh scale
- Flow transmitter
- Wearable fitness and activity monitor
- Blood glucose monitor
- Temperature sensing with RTD



Simplified Internal Schematic

3 Description

INA351A is a fixed gain of 10 instrumentation amplifier with a configurable reference amplifier in a small package. This instrumentation amp (INA) is built with precision-matched resistors to achieve excellent CMRR and gain error performance in a small, lowcost form factor. This makes INA351A a great solution to replace discrete INA implementations to achieve higher performance and more compact designs with minimal impact to bill of materials (BOM) costs.

The integrated, configurable reference amplifier can be used as a buffer for external use or as part of a closed-loop calibration circuit to achieve better DC precision. The closed-loop calibration can be accomplished by implementing a servo loop amplifier to calibrate DC errors from sensors (like offset, offset drift and so forth) at the INA output when the INA input signal is at a slightly higher frequency than DC depending on the application.

INA351A achieves 86 dB of minimum CMRR, an accurate 0.1% of maximum gain error and only consumes a maximum of 135 µA quiescent current at room temperature. The INA can directly drive sub-1 kHz, 10-bit to 14-bit, delta-sigma analog-to-digital converters (ADC) without an ADC driver, making it a great choice for portable, battery-powered medical applications like electrocardiograms or wearable health monitors.

Package Information

PART NUMBER ⁽³⁾	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾	
INA351A	DSG (WSON, 8)	2 mm × 2 mm	

- For all available packages, see the package option addendum at the end of the data sheet.
- (2)The package size (length × width) is a nominal value and includes pins, where applicable.
- See Device Comparison table.



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4 Revision History

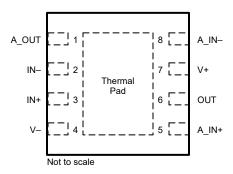
DATE	REVISION	NOTES
June 2023	*	Initial Release



5 Device Comparison Table

	NO. OF		
DEVICE	CHANNELS	WSON DSG	
INA351A	1	8	

6 Pin Configuration and Functions



Note: Connect Thermal Pad to (V-)

Figure 6-1. DSG Package, 8-Pin WSON With Exposed Thermal Pad (Top View)

Table 6-1. Pin Functions

Р	PIN		DESCRIPTION	
NAME	NO.	TYPE ⁽¹⁾	DESCRIPTION	
IN-	2	I	Instrumentation amplifier negative (inverting) input	
IN+	3	I	nstrumentation amplifier positive (non-inverting) input	
OUT	6	0	Instrumentation amplifier output	
A_IN+	5	I	Reference amplifier positive (non-inverting) input. This pin usually connects to a reference voltage externally.	
A_OUT	1	0	Reference amplifier output. This is connected internally to the 60 k Ω resistor of the INA which is also called as REF node.	
A_IN-	8	I	Reference amplifier negative (inverting) input.	
V-	4	_	Negative supply	
V+	7	_	Positive supply	

(1) I = input, O = output



7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Supply voltage, $V_S = (V+) - (V-)$		0	6	V
	Common mode voltage ⁽²⁾	(V-) - 0.5	(V+) + 0.5	V
Signal input pins	Differential voltage ⁽³⁾		V _S + 0.2	V
	Current ⁽²⁾	-10	10	mA
Output short-circuit ⁽⁴⁾		Continuou	IS	
Operating Temperature, T _A		-55	150	
Junction Temperature, T _J			150	°C
Storage Temperature, T _{stg}		-65	150	

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Input pins are diode-clamped to the power-supply rails. Input signals that may swing more than 0.5 V beyond the supply rails must be current limited to 10 mA or less
- (3) Differential input voltages greater than 0.5 V applied continuously can result in a shift to the input offset voltage above the maximum specification of this parameter. The magnitude of this effect increases as the ambient operating temperature rises.
- (4) Short-circuit to V_S / 2.

7.2 ESD Ratings

				VALUE	UNIT
_\		Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
"	(ESD)	Lieurostatic discriarge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	, v

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Supply voltage \(\(- \lambda \)	Single-supply	1.8	5.5	V
Supply voltage $V_S = (V+) - (V-)$	Dual-supply	±0.9	±2.75	V
Input Voltage Range		(V-)	(V+)	V
Specified temperature	Specified temperature	-40	125	°C

7.4 Thermal Information

		INA351A	
	THERMAL METRIC ⁽¹⁾	DSG (WSON)	UNIT
		8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	80.3	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	100.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	46.4	°C/W
ΨЈТ	Junction-to-top characterization parameter	5.3	°C/W
ΨЈВ	Junction-to-board characterization parameter	46.4	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	21.9	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



7.5 Electrical Characteristics

For $V_S = (V+) - (V-) = 1.8 \text{ V}$ to 5.5 V (±0.9 V to ±2.75 V) at $T_A = 25^{\circ}\text{C}$, $V_{CM} = [(V_{IN+}) + (V_{IN-})] / 2 = V_S / 2$, $V_{IN} = (V_{IN+}) - (V_{IN-}) = 0 \text{ V}$, $V_{A_IN+} = V_S / 2$, $V_{A_IN-} = V_{A_OUT}$, G = 10, $R_L = 10 \text{ k}\Omega$ connected to $V_S / 2$, and $V_{OUT} = V_S / 2$ (unless otherwise noted)

noted)	PARAMETER	TEST CONDIT	IONS	MIN	TYP	MAX	UNIT
INPUT	.,						• • • • • • • • • • • • • • • • • • • •
	Offset Voltage, RTI ⁽¹⁾	V _S = 5.5 V	T _A = 25°C		±0.2	±1.3	mV
√ _{osi}	Offset Voltage over T,	V _S = 5.5 V	$T_A = 23 \text{ C}$ $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$		10.2	±1.4	mV
- 031	RTI ⁽¹⁾ Offset temp drift, RTI ⁽²⁾	V _S = 5.5 V	$T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$		±0.60		μV/°C
PSRR	Power-supply rejection ratio		T _A = 25°C		20	75	μV/V
Z _{IN-DM}	Differential Impedance				100 5		GΩ pF
Z _{IN-CM}	Common Mode Impedance				100 9		GΩ pF
V _{CM}	Input Stage Common Mode Range ⁽³⁾			(V-)		(V+)	V
		V _{CM} = (V–) + 0.1 V to (V+) – 1 V, High CMRR Region	V _S = 5.5 V	86	103		
CMRR DC	Common-mode rejection ratio, RTI	V _{CM} = (V–) + 0.1 V to (V+) – 1 V, High CMRR Region	V _S = 3.3 V		94		dB
		$V_{CM} = (V-) + 0.1 \text{ V to } (V+) - 0.1 \text{ V}$	V _S = 5.5 V	62	75		
BIAS CU	IRRENT	1	1				
l _B	Input bias current	V _{CM} = V _S / 2			±0.75		pA
I _{os}	Input offset current	$V_{CM} = V_S / 2$			±0.40		pA
NOISE V	OLTAGE						
	Input referred voltage	f = 1 kHz		36			
PNI	noise density ⁽⁵⁾	f = 10 kHz 35			nV/√ Hz		
E _{NI}	Input referred voltage noise ⁽⁵⁾	f _B = 0.1 Hz to 10 Hz			3.0		μV _{PP}
'n	Input current noise	f = 1 kHz			22		fA/√Hz
GAIN	'						
GE	Gain error ⁽⁴⁾	V _{REF} = V _S /2	$V_O = (V-) + 0.1 \text{ V to}$ (V+) - 0.1 V		±0.02	±0.10	%
OUTPUT	-						
V _{OH}	Positive rail headroom	$R_L = 10 \text{ k}\Omega \text{ to V}_S/2$			15	30	mV
V _{OL}	Negative rail headroom	$R_L = 10 \text{ k}\Omega \text{ to V}_S/2$			15	30	mV
C _L Drive	Load capacitance drive	V _O = 100 mV step, Overshoot < 20%	6		500		pF
Z _O	Closed-loop output impedance	f = 10 kHz			51		Ω
l _{sc}	Short-circuit current	V _S = 5.5 V			±20		mA
	NCY RESPONSE						
BW	Bandwidth, –3 dB	$V_{IN} = 10 \text{ mV}_{pk-pk}$			100		kHz
THD + N	Total harmonic distortion + noise	$V_S = 5.5 \text{ V}, V_{CM} = 2.75 \text{ V}, V_O = 1 \text{ V}_R$ f = 1 kHz, 80-kHz measurement BV			0.035		%
EMIRR	Electro-magnetic interference rejection ratio	f = 1 GHz, V _{IN_EMIRR} = 100 mV			96		dB
SR	Slew rate	$V_S = 5 \text{ V}, V_O = 2 \text{ V step}$			0.20		V/µs
		To 0.1%, V _S = 5.5 V, V _{STEP} = 2 V, C _L = 10 pF					
s	Settling time	To 0.01%, V _S = 5.5 V, V _{STEP} = 2 V, C _L = 10 pF			24		μs
	Overload recovery	V _{IN} = 1 V			8		μs
REFERE	NCE AMPLIFIER	<u> </u>					<u> </u>
REF -	Ref. input offset voltage	V _S = 5.5 V ⁽⁴⁾			±0.6	±2.25	mV
REF - V _{OS}	Ref. input offset voltage drift	V _S = 5.5 V			±0.8		μV/°C



7.5 Electrical Characteristics (continued)

For $V_S = (V+) - (V-) = 1.8 \text{ V}$ to 5.5 V ($\pm 0.9 \text{ V}$ to $\pm 2.75 \text{ V}$) at $T_A = 25^{\circ}\text{C}$, $V_{CM} = [(V_{IN+}) + (V_{IN-})] / 2 = V_S / 2$, $V_{IN} = (V_{IN+}) - (V_{IN-}) = 0 \text{ V}$, $V_{A_IN+} = V_S / 2$, $V_{A_IN-} = V_{A_OUT}$, $V_{A_OUT} = V_{A_OUT}$

	PARAMETER	TEST CONDIT	TONS	MIN	TYP	MAX	UNIT
REF - I _B	Ref. input bias current	V _S = 5.5 V			±1		pА
REF - Z _{INCM}	Ref. common mode input impedance				100 0.5		GΩ pF
REF - E _N	Ref. input voltage noise	f = 0.1 to 10 Hz			8.7		μV_{PP}
REF - e _N	Ref. input voltage noise density	f = 10 kHz			64		nV/√ Hz
REF - V _{IN}	Ref. input voltage range	V _S = 5.5 V		(V-)		(V+)	V
REF - A _{OL}	Ref. open loop voltage gain	(V-) + 0.1 V < V _O < (V+) - 0.1 V	V _S = 5.5 V		120		dB
REF - GBW	Ref. gain-bandwidth product	V _S = 5.5 V			360		kHz
REF - t _S	Ref. settling time	To 0.1%, V _S = 5.5 V, V _{STEP} = 2 V, G	To 0.1%, V _S = 5.5 V, V _{STEP} = 2 V, G = 1, C _L = 10 pF		25		μs
REF - PM	Ref. phase margin	V _S = 5.5 V, G = 1, C _L = 10 pF			65		0
REF - V _O	Ref. voltage output swing from rail	V _S = 5.5 V, G = 1				175	mV
REF - I _{SC}	Ref. short circuit current	V _S = 5.5 V, G = 1	V _S = 5.5 V, G = 1				mA
POWER	SUPPLY	ı				'	
Vs	Power-supply voltage	Single-supply		1.8		5.5	V
v S	i ower-supply voltage	Dual-supply	·	±0.85	· ·	±2.75	V
Ιο	Quiescent current	V _{IN} = 0 V			110	135	μA
·Q	gaiosooni ourroni	$T_A = -40^{\circ}C$ to 125°C	= -40°C to 125°C			147	μ, ι

- (1)
- Total offset, referred-to-input (RTI): $V_{OS} = (V_{OSI}) + (V_{OSO} / G)$. Offset drifts are uncorrelated. Input-referred offset drift is calculated using: $\Delta V_{OS(RTI)} = \sqrt{[\Delta V_{OSI}]^2 + (\Delta V_{OSO} / G)^2}$ (2)
- Input common mode voltage range of the just the input stage of the instrumentation amplifier. The entire INA351 input range depends on the combination input common-mode voltage, differential voltage, gain, A_OUT voltage and power supply voltage. Typical Characteristic curves will be added with more information.
- Min and Max values are specified by characterization.
- Total RTI voltage noise is equal to: $e_{N(RTI)} = \sqrt{[e_{NI}]^2 + (e_{NO}/G)^2}$

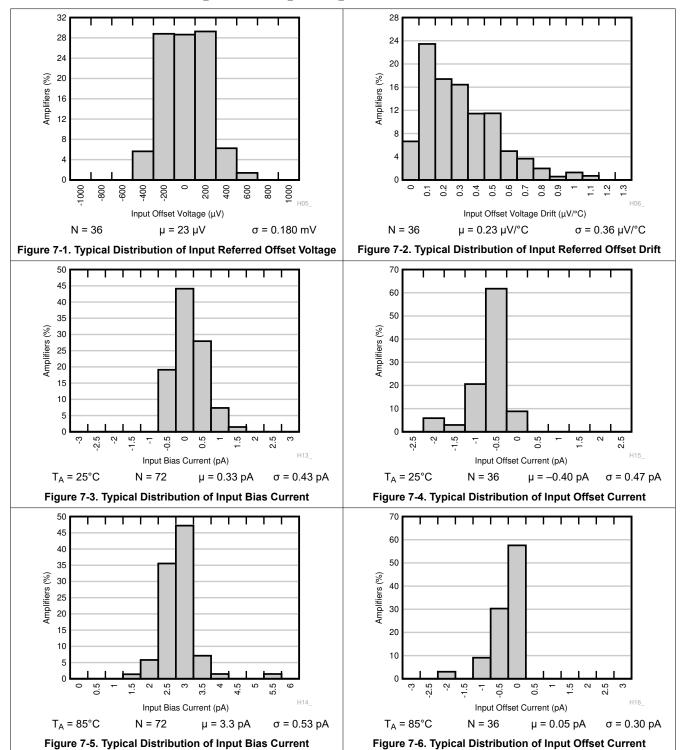
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7.6 Typical Characteristics

at T_A = 25°C, V_S = (V+) - (V-) = 5.5 V, V_{IN} = (V_{IN+}) - (V_{IN-}) = 0 V, R_L = 10 k Ω , C_L = 10 pF, V_{REF} = V_S / 2, V_{CM} = [(V_{IN+}) + (V_{IN-})] / 2 = V_S / 2, V_{OUT} = V_S / 2, V_{A_IN+} = V_S / 2, V_{A_OUT} = V_{A_IN+} and V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+}





at T_A = 25°C, V_S = (V+) - (V-) = 5.5 V, V_{IN} = (V_{IN+}) - (V_{IN-}) = 0 V, R_L = 10 k Ω , C_L = 10 pF, V_{REF} = V_S / 2, V_{CM} = [(V_{IN+}) + (V_{IN-})] / 2 = V_S / 2, V_{OUT} = V_S / 2, V_{A_IN+} = V_S / 2, V_{A_OUT} = V_{A_IN+} and V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+}

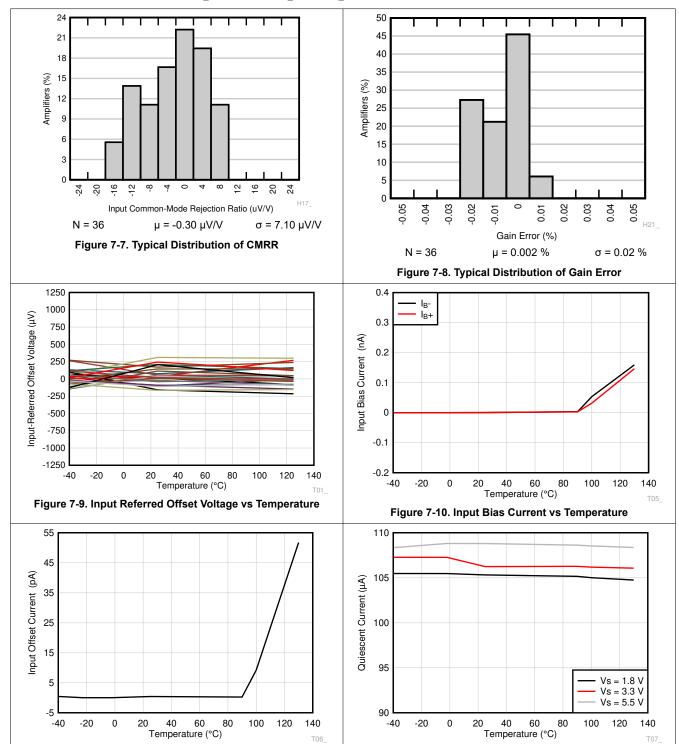
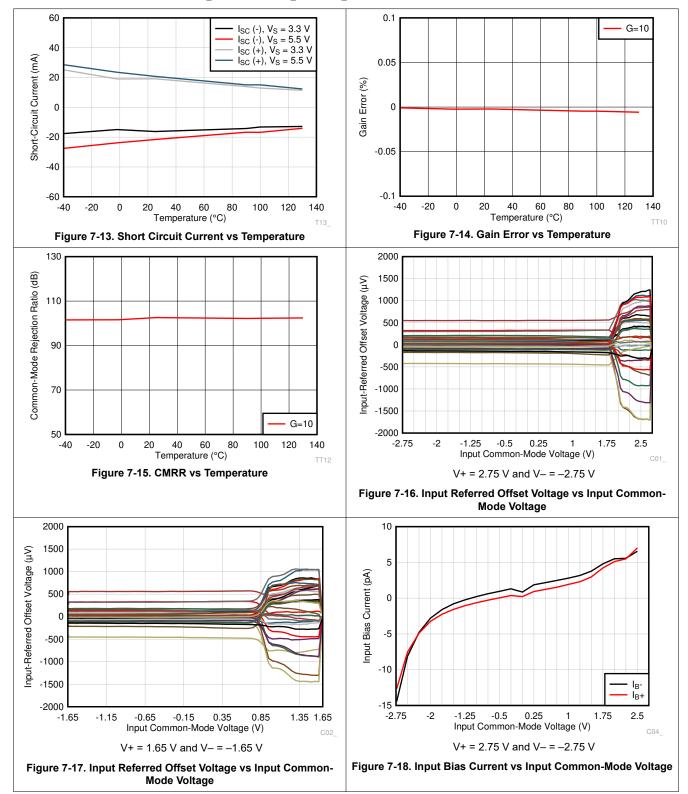


Figure 7-11. Input Offset Current vs Temperature

Figure 7-12. Quiescent Current vs Temperature



at T_A = 25°C, V_S = (V+) - (V-) = 5.5 V, V_{IN} = (V_{IN+}) - (V_{IN-}) = 0 V, R_L = 10 k Ω , C_L = 10 pF, V_{REF} = V_S / 2, V_{CM} = [(V_{IN+}) + (V_{IN-})] / 2 = V_S / 2, V_{OUT} = V_S / 2, V_{A_IN+} = V_S / 2, V_{A_OUT} = V_{A_IN+} and V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+}





at T_A = 25°C, V_S = (V+) - (V-) = 5.5 V, V_{IN} = (V_{IN+}) - (V_{IN-}) = 0 V, R_L = 10 k Ω , C_L = 10 pF, V_{REF} = V_S / 2, V_{CM} = [(V_{IN+}) + (V_{IN-})] / 2 = V_S / 2, V_{OUT} = V_S / 2, V_{A_IN+} = V_S / 2, V_{A_OUT} = V_{A_IN+} and V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} = 0 v, V_{A_IN+} and V_{A_IN+} = 0 v, V_{A_IN+}

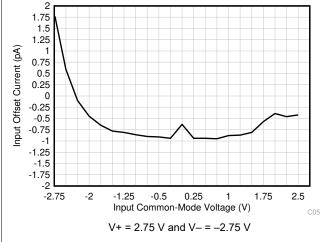


Figure 7-19. Input Offset Current vs Input Common-Mode Voltage

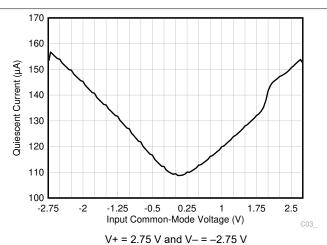


Figure 7-20. Quiescent Current vs Input Common-Mode Voltage

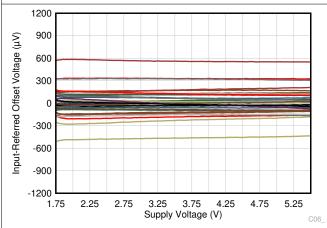


Figure 7-21. Input Referred Offset Voltage vs Supply Voltage

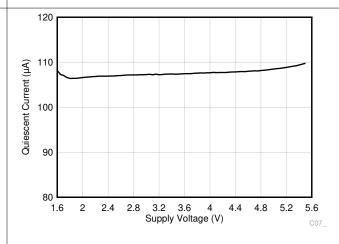
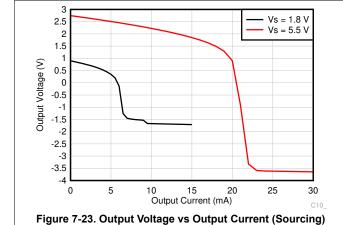


Figure 7-22. Quiescent Current vs Supply Voltage



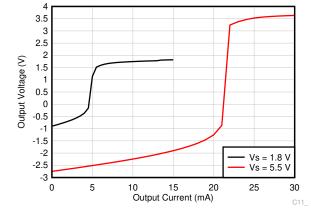
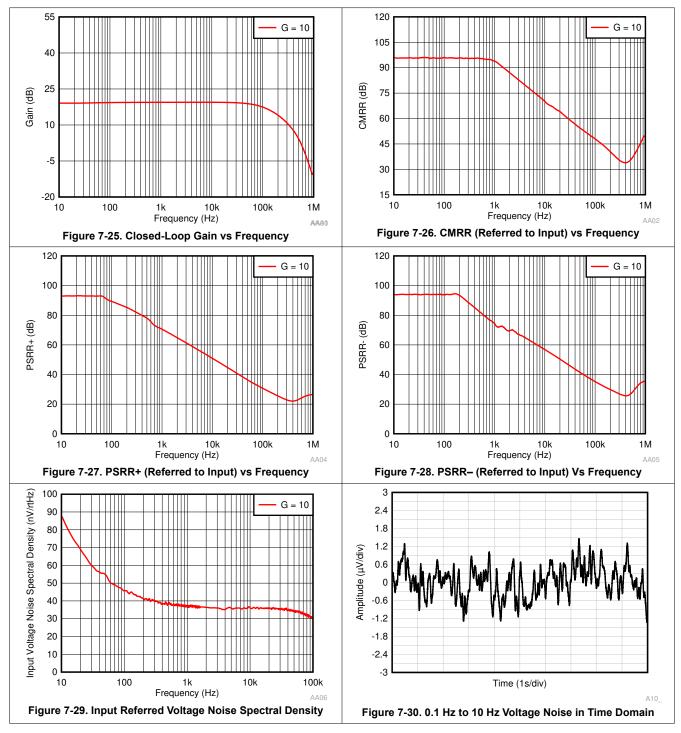


Figure 7-24. Output Voltage vs Output Current (Sinking)

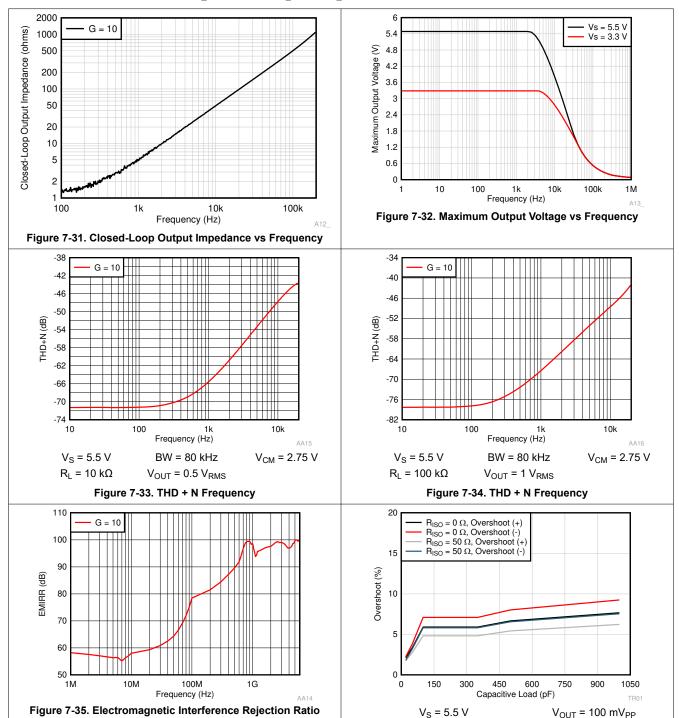


at T_A = 25°C, V_S = (V+) - (V-) = 5.5 V, V_{IN} = (V_{IN+}) - (V_{IN-}) = 0 V, R_L = 10 k Ω , C_L = 10 pF, V_{REF} = V_S / 2, V_{CM} = [(V_{IN+}) + (V_{IN-})] / 2 = V_S / 2, V_{OUT} = V_S / 2, V_{A_IN+} = V_S / 2, V_{A_OUT} = V_{A_IN+} and V_{A_IN-} and V_{A_IN-} and V_{A_IN-} = 0 v, V_{A_IN-} and V_{A_IN-} = 0 v, V_{A_IN-} and V_{A_IN-} and V_{A_IN-} = 0 v, V_{A_IN-} =





at $T_A = 25^{\circ}C$, $V_S = (V+) - (V-) = 5.5 \text{ V}$, $V_{IN} = (V_{IN+}) - (V_{IN-}) = 0 \text{ V}$, $R_L = 10 \text{ k}\Omega$, $C_L = 10 \text{ pF}$, $V_{REF} = V_S / 2$, $V_{CM} = [(V_{IN+}) + (V_{IN-})] / 2 = V_S / 2$, $V_{OUT} = V_S / 2$, $V_{A_IN+} = V_S / 2$, $V_{A_OUT} = V_{A_IN-}$ and G = 10 (unless otherwise noted)

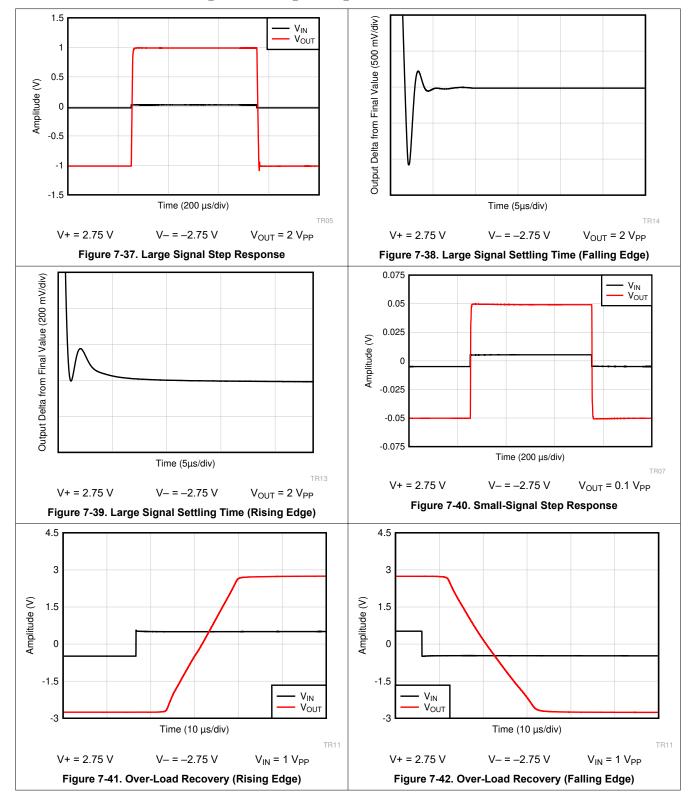


Referred to Noninverting Input (EMIRR+) vs Frequency

Figure 7-36. Small-Signal Overshoot vs Capacitive Load



at $T_A = 25^{\circ}C$, $V_S = (V+) - (V-) = 5.5$ V, $V_{IN} = (V_{IN+}) - (V_{IN-}) = 0$ V, $R_L = 10$ k Ω , $C_L = 10$ pF, $V_{REF} = V_S / 2$, $V_{CM} = [(V_{IN+}) + (V_{IN-})] / 2 = V_S / 2$, $V_{OUT} = V_S / 2$, $V_{A_IN+} = V_S / 2$, $V_{A_OUT} = V_{A_IN+}$ and G = 10 (unless otherwise noted)





at $T_A = 25^{\circ}C$, $V_S = (V+) - (V-) = 5.5$ V, $V_{IN} = (V_{IN+}) - (V_{IN-}) = 0$ V, $R_L = 10$ k Ω , $C_L = 10$ pF, $V_{REF} = V_S / 2$, $V_{CM} = [(V_{IN+}) + (V_{IN-})] / 2 = V_S / 2$, $V_{OUT} = V_S / 2$, $V_{A_IN+} = V_S / 2$, $V_{A_OUT} = V_{A_IN+}$ and G = 10 (unless otherwise noted)

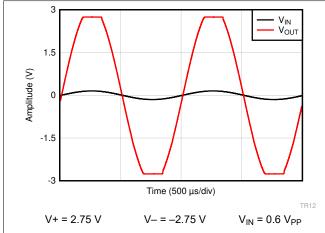


Figure 7-43. No Phase Reversal

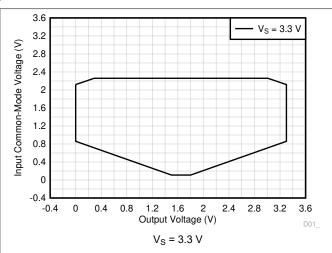


Figure 7-44. Input Common-Mode Voltage vs Output Voltage (High CMRR Region)

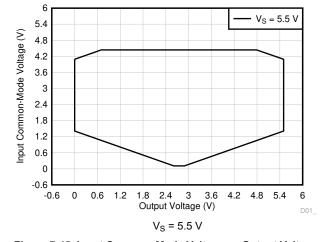


Figure 7-45. Input Common-Mode Voltage vs Output Voltage (High CMRR Region)

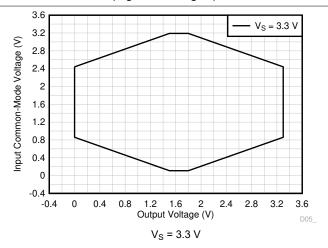


Figure 7-46. Input Common-Mode Voltage vs Output Voltage

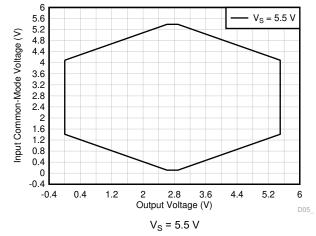


Figure 7-47. Input Common-Mode Voltage vs Output Voltage



8 Detailed Description

8.1 Overview

INA351A is a G = 10 instrumentation amplifier with configurable reference amplifier designed to provide an integrated, small size, cost-effective solution for applications employing discrete implementation of INA using commodity amplifiers and resistors. This integrated instrumentation amplifier is built using four operational amplifiers and seven precision matched integrated resistors. With 86dB minimum CMRR and 0.1% maximum gain error, INA351A is suitable to be used directly in sub 10-bit systems without any external calibration. Additional calibration of offset and gain error at a system level can further improve system resolution and accuracy, enabling use in 12-bit to 14-bit precision applications.

INA351A has a configurable reference amplifier with external input and output pins. This reference amplifier's output is connected to the 60-k Ω internal resistor so that any reference voltage on the amplifier input that sets the output common mode of the INA could be buffered. This buffered output voltage is available externally and could be used to bias subsequent amplifier stages.

More importantly, the reference amplifier enables DC error calibration when configured in a servo loop. When the INA input signal is at a slightly higher frequency than DC, the servo amplifier can enable external calibration of total DC errors (offset, drift etc.) at the INA output leading to a overall better DC precision. The INA351A in calibration loop is well suited for medical applications where the low-frequency signals like ECG, EEG, EMG are to be amplified with relatively lower noise and lesser DC errors. It is also suitable for use in industrial applications in higher frequency pressure transducers and lock in amplifier designs.

One of the key features of INA351A is that the device does not need any external resistors to set the gain. Often these external resistors require tighter tolerance and careful routing, which adds to system complexity and cost. The device is highly suitable for voltage sensing in space-constrained applications such as patient monitoring, sleep diagnostics, electronic hospital beds, and blood glucose monitoring. INA351A can enable these systems to reduce their overall size and cost while providing optimal performance.

8.2 Functional Block Diagram

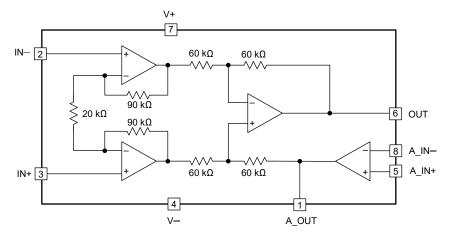


Figure 8-1. Simplified Internal Schematic

8.3 Feature Description

8.3.1 Gain-Setting

8.3.1.1 Gain Error and Drift

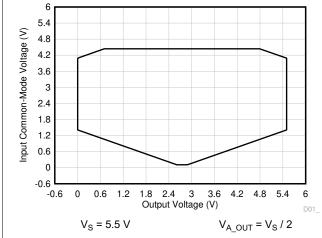
Gain error in INA351A is limited by the mismatch of the integrated precision resistors and is specified based on characterization results. Gain error of maximum 0.1% can be expected for this INA. Gain drift in INA351A is limited by the slight mismatch of the temperature coefficient of the integrated resistors. Since these integrated resistors are precision matched with low temperature coefficient resistors to begin with, the overall gain drift is much better in comparison to discrete implementation of the instrumentation amplifiers built using external resistors.

8.3.2 Input Common-Mode Voltage Range

INA351A has two gain stages, the first stage has a common-mode gain of 1 and a differential gain of 10. The second stage is configured in a difference-amplifier configuration with differential gain of 1 and ideally rejects all of the input common mode completely. The second stage also provides a gain of 1 from voltage at A OUT to set the output common-mode voltage.

The linear input voltage range of the INA351A, even for a rail-to-rail first stage, is dictated by both the signal swing at output of the first stage as well as the input common-mode voltage range output swing of the second stage. In order to maximize performance, it is critical to keep the INA351A within its linear range for a given combination of reference amp's output voltage (A OUT connects to REF), and input common-mode voltage for a particular input differential. Input common-mode voltage (V_{CM}) vs output voltage graphs (V_{OUT}) in this section show a particular A OUT voltage and gain configuration to outline the linear performance region of INA351A. A good common-mode rejection can be expected when operating with in the limits of the V_{CM} vs V_{OUT} graph. Note that the INA351A linear input voltage cannot be close to or extend beyond the supply rails, as the output of the first stage will be driven into saturation.

The common-mode range for the most common operating conditions is outlined in the following figures. Figure 8-2 shows the region of operation where a minimum of 86 dB can be achieved. Figure 8-3 has much wider region of operation with a lower minimum CMRR of 62 dB, because the input signal crosses over the transition region of the input pairs to achieve rail-to-rail operation. The common-mode range for other operating conditions is best calculated with the INA V_{CM} vs V_{OUT} tool located under the Amplifiers and Comparators section of the Analog Engineer's Calculator on ti.com. INA351-HCM model can be specifically used for applications requiring high CMRR and corresponds to performance shown in Figure 8-2. INA351xxS model can be used for applications where the input common mode can be expected to vary rail-to-rail and the model corresponds to performance shown in Figure 8-3, where CMRR drops to 62-dB minimum.



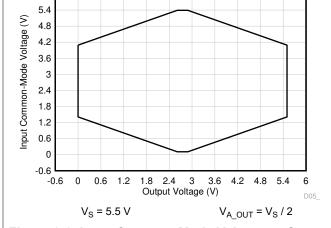


Figure 8-2. Input Common-Mode Voltage vs Output | Figure 8-3. Input Common-Mode Voltage vs Output **Voltage (High CMRR Region)**

Voltage



8.3.3 EMI Rejection

The INA351A uses integrated electromagnetic interference (EMI) filtering to reduce the effects of EMI from sources such as wireless communications and densely-populated boards with a mix of analog signal chain and digital components. EMI immunity can be improved with circuit design techniques; the INA351A benefits from these design improvements. Texas Instruments has developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10 MHz to 6 GHz. Figure 8-4 shows the results of this testing on the INA351A. Table 8-1 provides the EMIRR IN+ values for the INA351A at particular frequencies commonly encountered in real-world applications. The *EMI Rejection Ratio of Operational Amplifiers* application report contains detailed information on the topic of EMIRR performance relating to op amps and is available for download from www.ti.com.

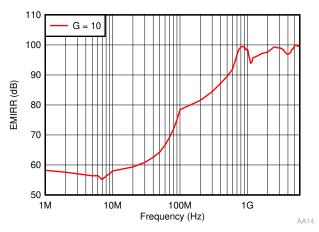


Figure 8-4. EMIRR Testing

Table 8-1. INA351A EMIRR IN+ for Frequencies of Interest

FREQUENCY	APPLICATION OR ALLOCATION	EMIRR IN+
400 MHz	Mobile radio, mobile satellite, space operation, weather, radar, ultra-high frequency (UHF) applications	
900 MHz	Global system for mobile communications (GSM) applications, radio communication, navigation, GPS (to 1.6 GHz), GSM, aeronautical mobile, UHF applications	99 dB
1.8 GHz	GSM applications, mobile personal communications, broadband, satellite, L-band (1 GHz to 2 GHz)	97 dB
2.4 GHz	802.11b, 802.11g, 802.11n, Bluetooth®, mobile personal communications, industrial, scientific and medical (ISM) radio band, amateur radio and satellite, S-band (2 GHz to 4 GHz)	98 dB
3.6 GHz	Radiolocation, aero communication and navigation, satellite, mobile, S-band	97 dB
5 GHz	802.11a, 802.11n, aero communication and navigation, mobile communication, space and satellite operation, C-band (4 GHz to 8 GHz)	99 dB

8.3.4 Typical Specifications and Distributions

Designers often have questions about a typical specification of an amplifier to design a more robust circuit. Due to natural variation in process technology and manufacturing procedures, every specification of an amplifier exhibits some amount of deviation from the ideal value, like an amplifier's input offset voltage. These deviations often follow *Gaussian* (*bell curve*), or *normal* distributions, and circuit designers can leverage this information to guard band their system, even when there is not a minimum or maximum specification in the *Electrical Characteristics* table.



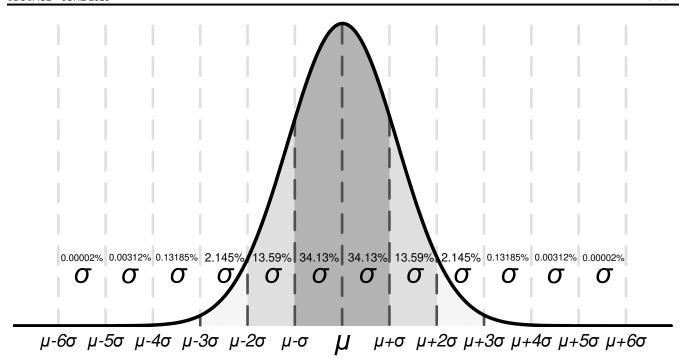


Figure 8-5. Ideal Gaussian Distribution

Figure 8-5 shows an example distribution, where μ , or mu, is the mean of the distribution, and where σ , or sigma, is the standard deviation of a system. For a specification that exhibits this kind of distribution, approximately two-thirds (68.26%) of all units can be expected to have a value within one standard deviation, or one sigma, of the mean (from $\mu - \sigma$ to $\mu + \sigma$).

Depending on the specification, values listed in the *typical* column of the *Electrical Characteristics* table are represented in different ways. As a general rule, if a specification naturally has a nonzero mean (for example, like gain bandwidth), then the typical value is equal to the mean (μ). However, if a specification naturally has a mean near zero (like input offset voltage), then the typical value is equal to the mean plus one standard deviation (μ + σ) to most accurately represent the typical value.

Designers can use this chart to calculate approximate probability of a specification in a unit; for example, the INA351A typical input referred voltage offset is 200 μ V, so 68.2% of all INA351A devices are expected to have an offset from –200 μ V to +200 μ V. At 4 σ (±800 μ V), 99.9937% of the distribution has an offset voltage less than ±800 μ V, which means 0.0063% of the population is outside of these limits, which corresponds to about 1 in 15,873 units.

Specifications with a value in the minimum or maximum column are verified by TI, and units outside these limits are removed from production material. For example, the INA351A family has a maximum offset voltage of 1.3 mV at 25°C, and even though this corresponds to 6 σ (\approx 1 in 500 million units), which is extremely unlikely, TI verifies that any unit with larger offset than 1.3 mV are removed from production material.

For specifications with no value in the minimum or maximum column, consider selecting a sigma value of sufficient guard band for the designers application, and design worst-case conditions using this value. As stated earlier, the 6- σ value corresponds to about 1 in 500 million units, which is an extremely unlikely chance, and can be an option as a wide guard band to design a system around. In this case, the INA351A family does not have a maximum or minimum for offset voltage drift, but based on Figure 7-2 and the typical value of 0.65 μ V/°C in the *Electrical Characteristics* table, the 6- σ value for offset voltage drift can be calculated to 3.9 μ V/°C. When designing for worst-case system conditions, this value can be used to estimate the worst possible offset drift without having an actual minimum or maximum value.



However, process variation and adjustments over time can shift typical means and standard deviations, and unless there is a value in the minimum or maximum specification column, TI cannot verify the performance of a device. This information must be used only to estimate the performance of a device.

8.3.5 Electrical Overstress

Designers often ask questions about the capability of an operational amplifier to withstand electrical overstress. These questions tend to focus on the device inputs, but can involve the supply voltage pins or even the output pin. Each of these different pin functions have electrical stress limits determined by the voltage breakdown characteristics of the particular semiconductor fabrication process and specific circuits connected to the pin. Additionally, internal electrostatic discharge (ESD) protection is built into these circuits to protect them from accidental ESD events both before and during product assembly.

Having a good understanding of this basic ESD circuitry and the relevance to an electrical overstress event is helpful. Figure 8-6 shows the ESD circuits contained in the INA351A devices. The ESD protection circuitry involves several current-steering diodes connected from the input and output pins and routed back to the internal power supply lines, where these diodes meet at an absorption device internal to the operational amplifier. This protection circuitry is intended to remain inactive during normal circuit operation.

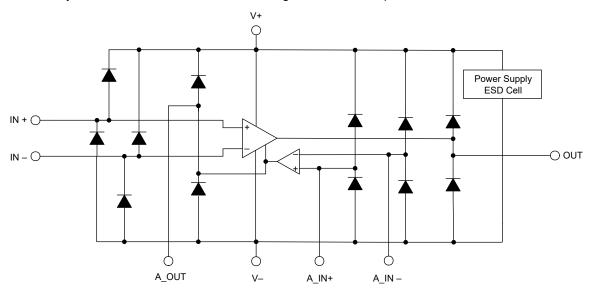


Figure 8-6. Equivalent Internal ESD Circuitry

8.4 Device Functional Modes

INA351A has only one functional mode. The device can be powered in single supply or dual supply configurations as long as the device is supplied with $V_S = (V+) - (V-) = 1.8 \text{ V}$ to 5.5 V as specified in the recommended operating conditions.

9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

9.1.1 Reference Amplifier

The output voltage of the INA351A is developed with respect to the voltage on the pin A_OUT. The voltage on the A_OUT pin sets the common-mode voltage of the instrumentation amplifier OUT pin. In single-supply operation with a bipolar input, setting the output common-mode to a precise mid-supply level is useful and required (for example, 2.75-V in a 5.5-V supply environment) to allow the output signal to swing negative and positive in equal proportions. Traditionally, this is accomplished using a resistive divider from supply and an external reference buffer.

In INA351A, the reference amplifier is integrated on-chip and it is sufficient to only have the resistive divider from supply. With that, the reference amplifier can be connected in G = 1 as shown in Figure 9-1 to provide buffered reference voltage internally to the INA as well as to additional circuits for external use.

Moreover, INA351A has a provision to include servo loop based calibration for external DC offset, drift from the sensor as well as the internal INA offset, drift. This is accomplished using the internal reference amplifier and the three external passive components (R_1 , R_2 , and C_2) as shown in Figure 9-2. The ratio of resistors R_2 with respect to R_1 sets the gain in the calibration loop to attenuate the DC errors at lower frequencies around DC. At higher frequencies, the capacitor, C_2 shorts R_2 to put the reference buffer in G=1. This enables the instrumentation amplifier's input differential voltage to influence the INA output at higher frequencies while the reference amplifier in servo loop influences the INA output at lower frequencies around DC. Care should be taken to limit the gain in servo loop so as to maintain sufficient stability. Also, the value of C_2 , R_2 should be chosen based on the frequency of input signal at the INA input. Now, the resulting residual DC error after calibration would be that of the reference amplifier itself which is minor in comparison to higher DC offset from the instrumentation amplifier, sensor.

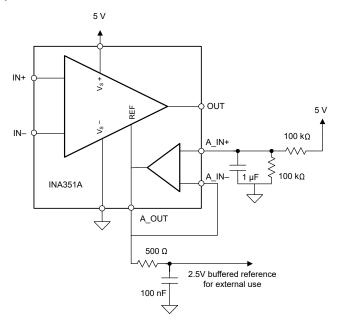


Figure 9-1. INA351A in Reference Buffer Configuration



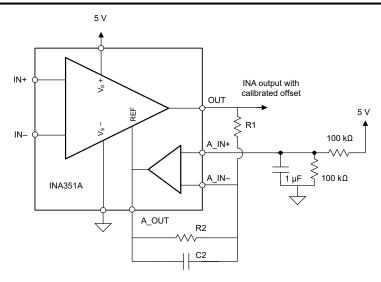


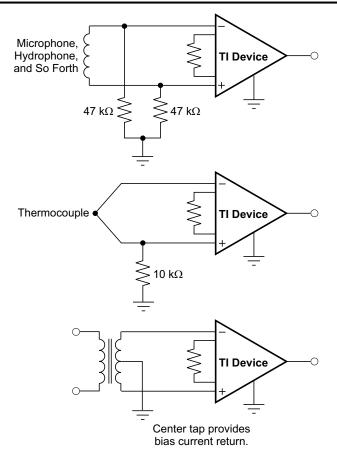
Figure 9-2. INA351A in Servo-Loop Calibration Configuration

9.1.2 Input Bias Current Return Path

The input impedance of the INA351A is extremely high, but a path must be provided for the input bias current of both inputs. This input bias current is typically a few pico amps but at high temperature this can be a few nano amps. High input impedance means that the input bias current changes little with varying input voltage.

For proper operation, input circuitry must provide a path for this input bias current. Figure 9-3 shows various provisions for an input bias current path. Without a bias current path, the inputs float to a potential that exceeds the common-mode range of the INA351A, and the input amplifiers saturate. If the differential source resistance is low, the bias current return path connects to one input (as shown in the thermocouple example in Figure 9-3). With a higher source impedance, use two equal resistors to provide a balanced input, with the possible advantages of a lower input offset voltage as a result of bias current, and better high-frequency common-mode rejection.





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Figure 9-3. Providing an Input Common-Mode Current Path



9.2 Typical Applications

9.2.1 Resistive-Bridge Pressure Sensor

The INA351A is an integrated instrumentation amplifier that measures small differential voltages while simultaneously rejecting larger common-mode voltages. The device offers a low power consumption of 110 μ A (typical) and has a smaller form factor.

The device is designed for portable applications where sensors measure physical parameters, such as changes in fluid, pressure, temperature, or humidity. An example of a pressure sensor used in the medical sector is in portable infusion pumps or dialysis machines.

The pressure sensor is made of a piezo-resistive element that can be derived as a classical 4-resistor Wheatstone bridge.

Occlusion (infusion of fluids, medication, or nutrients) happens only in one direction, and therefore can only cause the resistive element (R) to expand. This expansion causes a change in voltage on one leg of the Wheatstone bridge, which induces a differential voltage V_{DIFF} .

Figure 9-4 shows an example circuit for an occlusion pressure sensor application, as required in infusion pumps. When blockage (occlusion) occurs against a set-point value, the tubing depresses, thus causing the piezo-resistive element to expand. The signal chain connected to the bridge downstream processes the pressure change and can trigger an alarm.

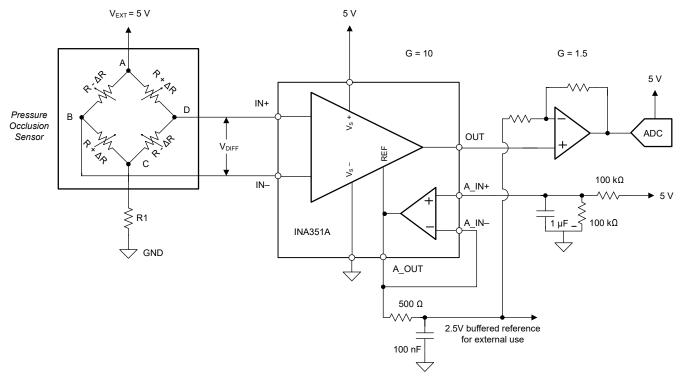


Figure 9-4. Resistive-Bridge Pressure Sensor

Low-tolerance bridge resistors must be used to minimize the offset and gain errors.

Given that there is only a positive differential voltage applied, this circuit is laid out in single-ended supply mode. The excitation voltage, V_{EXT} , to the bridge must be precise and stable; otherwise, measurement errors can be introduced.

9.2.1.1 Design Requirements

For this application, the design requirements are provided in Table 9-1.

Table 9-1. Design Requirements

DESCRIPTION	VALUE				
Single supply voltage	V _S = 5.0 V				
Excitation voltage	V _{EXT} = 5.0 V				
Occlusion pressure range	P = 1 psi to 12 psi, increments of P = 0.5 psi				
Occlusion pressure sensitivity	S = 2 ±0.5 (25%) mV/V/psi				
Occlusion pressure impedance (R)	$R = 4.99 \text{ k}\Omega \pm 50 \Omega (0.1\%)$				
Total pressure sampling rate	Sr = 20 Hz				
ADC supply voltage	V _{ADC(fs)} = 5.0 V				
Full-scale range of ADC	V _{OUT} = 0.25 V to 4.75 V to avoid saturation				

9.2.1.2 Detailed Design Procedure

This section provides basic calculations to lay out the instrumentation amplifier with respect to the given design requirements.

One of the key considerations in resistive-bridge sensors is the common-mode voltage, V_{CM} . If the bridge is balanced (no pressure, thus no voltage change), $V_{CM(zero)}$ is half of the bridge excitation (V_{EXT}). In this example $V_{CM (zero)}$ is 2.5 V. For the maximum pressure of 12 psi, the bridge common-mode voltage, $V_{CM (MAX)}$, is calculated by:

$$V_{CM(MAX)} = \frac{V_{DIFF}}{2} + V_{CM(zero)} \tag{1}$$

where

$$V_{DIFF} = S_{MAX} \times V_{EXT} \times P_{MAX} = 2.5 \frac{mV}{V \times psi} \times 5 V \times 12 psi = 150 mV$$
 (2)

Thus, the maximum common-mode voltage applied results in:

$$V_{CM(MAX)} = \frac{150 \, mV}{2} + 2.5 \, V = 2.575 \, V \tag{3}$$

Similarly, the minimum common-mode voltage can be calculated as,

$$V_{CM(MIN)} = \frac{-150 \, mV}{2} + 2.5 \, V = 2.425 \, V \tag{4}$$

The next step is to calculate the gain required for the given maximum sensor output voltage span, V_{DIFF} , in respect to the required V_{OUT} swing of maximum 4.75V to avoid saturating the amplifier and the ADC running at 5V supply.

The following equation calculates the gain value using the maximum input voltage and the required output voltage:

$$G = \frac{V_{OUT}}{V_{DIFF(MAX)}} = \frac{2.25 \, V}{150 \, mV} = 15 \, V/V \tag{5}$$

Considering, INA351A is an INA in G = 10, an additional gain stage in G = 1.5 is added.

Next, let us make sure that the INA351A can operate within this range checking the *Input Common-Mode Voltage vs Output Voltage* curves in the *Typical Characteristics* section. The relevant figure is also in this section for convenience. Looking at Figure 9-5, we can confirm that a output signal swing of 3 V is supported for the input signal swing between 2.425 V and 2.575 V, thus making sure of the linear operation.

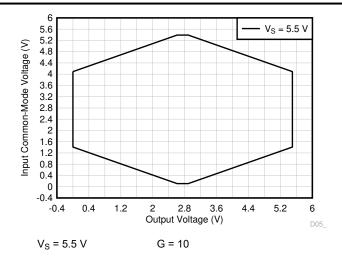


Figure 9-5. Input Common-Mode Voltage vs Output Voltage (High CMRR Region)

An additional series resistor in the Wheatstone bridge string (R1) may or may not be required, and can be decided based on the intended output voltage swing for a particular combination of supply voltage, reference voltage and the selected gain for an input common mode voltage range. R1 helps adjust the input commonmode voltage range, and thus can help accommodate the intended output voltage swing. In this particular example, it is not required and can be shorted out.

9.2.1.3 Application Curves

The following typical characteristic curve is for the circuit in Figure 9-4.

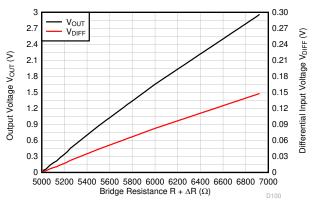


Figure 9-6. Input Differential Voltage, Output Voltage vs Bridge Resistance

9.3 Power Supply Recommendations

The nominal performance of the INA351A is specified with a supply voltage of ±2.75 V. The device also operates using power supplies from ±0.9 V (1.8 V) to ±2.75 V (5.5 V) with excellent performance. Parameters can vary significantly with operating voltage.



9.4 Layout

9.4.1 Layout Guidelines

Attention to good layout practices is always recommended. For best operational performance of the device, use the following PCB layout practices:

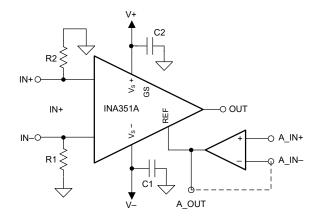
- Make sure that both input paths are well-matched for source impedance and capacitance to avoid converting common-mode signals into differential signals.
- Use bypass capacitors to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for singlesupply applications.
- Route the input traces as far away from the supply and output traces as possible to reduce parasitic coupling.
 If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better than crossing in parallel with the noisy trace.
- Place the external components as close to the device as possible.
- · Keep the traces as short as possible.

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9.4.2 Layout Example



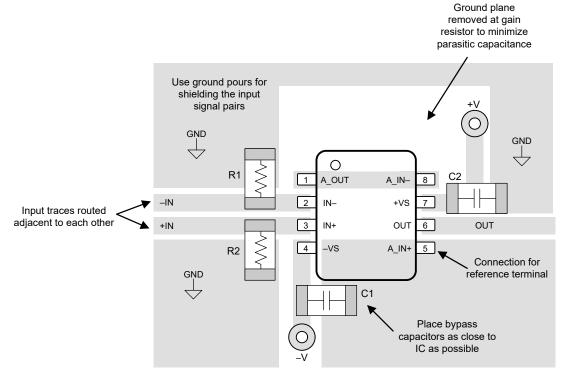


Figure 9-7. Example Schematic and Associated PCB Layout



10 Device and Documentation Support

10.1 Device Support

10.1.1 Development Support

- SPICE-based analog simulation program TINA-TI software folder
- Analog Engineers Calculator

10.1.1.1 PSpice® for TI

PSpice® for TI is a design and simulation environment that helps evaluate performance of analog circuits. Create subsystem designs and prototype solutions before committing to layout and fabrication, reducing development cost and time to market.

10.2 Documentation Support

10.2.1 Related Documentation

For related documentation see the following:

· Texas Instruments, EMI Rejection Ratio of Operational Amplifiers application report

10.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.4 Support Resources

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10.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.7 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 9-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
INA351AIDSGR	Active	Production	WSON (DSG) 8	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2TSH
INA351AIDSGR.A	Active	Production	WSON (DSG) 8	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2TSH

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

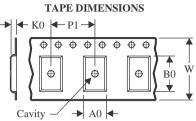
⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

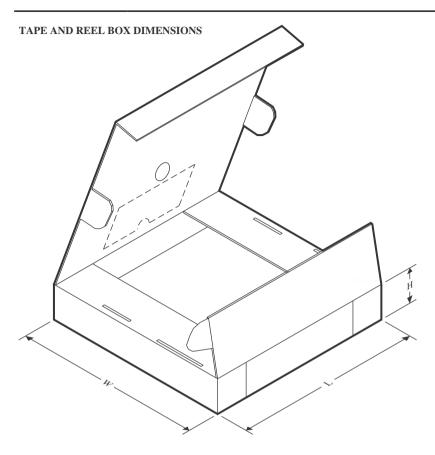


*All dimensions are nominal

Device	U	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA351AIDSGR	WSON	DSG	8	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2

PACKAGE MATERIALS INFORMATION

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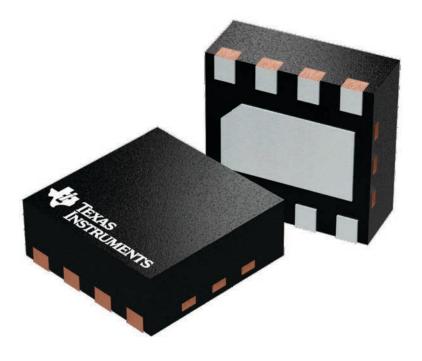
*All dimensions are nominal

Ì	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
ı	INA351AIDSGR	WSON	DSG	8	3000	210.0	185.0	35.0	

2 x 2, 0.5 mm pitch

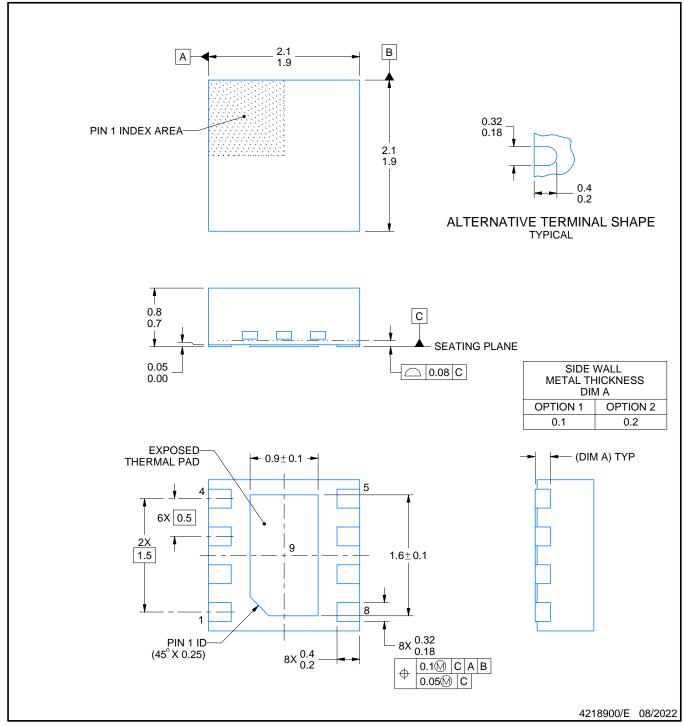
PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC SMALL OUTLINE - NO LEAD

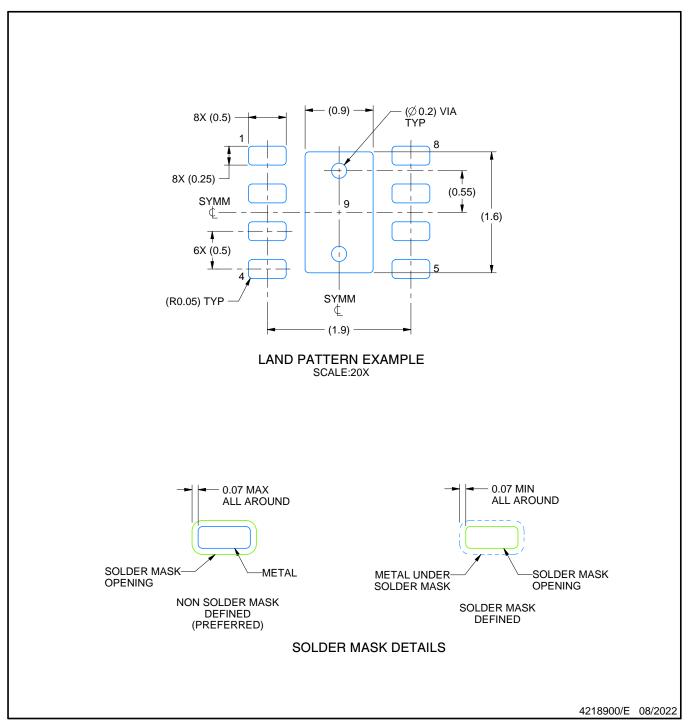


NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC SMALL OUTLINE - NO LEAD

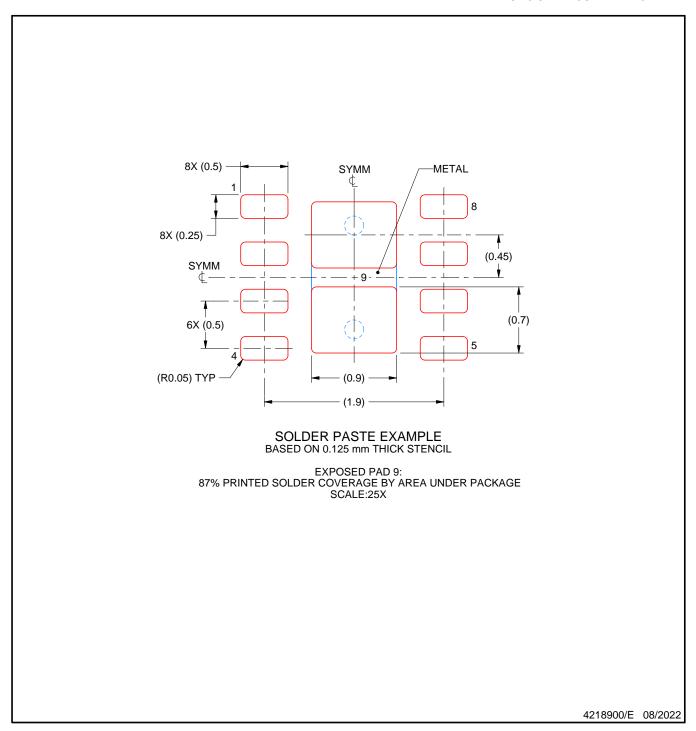


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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